SCES550B-FEBRUARY 2004-REVISED JUNE 2005

FEATURES

- Member of the Texas Instruments Widebus+™
 Family
- DOC[™] Circuitry Dynamically Changes Output Impedance, Resulting in Noise Reduction Without Speed Degradation
- Dynamic Drive Capability Is Equivalent to Standard Outputs With I_{OH} and I_{OL} of
 - $-\pm 24$ mA at 3-V V_{CC}
 - $-\pm15$ mA at 2.3-V V_{CC}
 - $-\pm 9$ mA at 1.65-V V_{CC}
 - $-\pm 6$ mA at 1.4-V V_{CC}
- Control Inputs V_{IH}/V_{IL} Levels Are Referenced to V_{CCB} Voltage
- If Either V_{CC} Input Is at GND, Both Ports Are in the High-Impedance State

- Inputs/Outputs Can Tolerate up to 4.6 V, Which Allows Mixed-Voltage-Mode Data Communications
- I_{off} Supports Partial-Power-Down Mode Operation
- Fully Configurable Dual-Rail Design Allows Each Port to Operate Over Full 1.4-V to 3.6-V Power-Supply Range
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DESCRIPTION/ORDERING INFORMATION

This 32-bit noninverting bus transceiver uses two separate configurable power-supply rails. The A port is designed to track V_{CCA} . V_{CCA} accepts any supply voltage from 1.4 V to 3.6 V. The B port is designed to track V_{CCB} . V_{CCB} accepts any supply voltage from 1.4 V to 3.6 V. This allows for universal low-voltage bidirectional translation between any of the 1.5-V, 1.8-V, 2.5-V, and 3.3-V voltage nodes.

The SN74AVCBH324245 is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (OE) input is used to disable the outputs, so the buses effectively are isolated.

The SN74AVCBH324245 is designed so that the control pins (1DIR, 2DIR, 1OE, and 2OE) are supplied by V_{CCB}.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CCB} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. If either V_{CC} input is at GND, both ports are in the high-impedance state.

ORDERING INFORMATION

T _A	PACKA	GE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	LFBGA – GKE	Tape and reel	SN74AVCBH324245KR	WN4245
-40 C 10 65 C	LFBGA – ZKE	Tape and reel	74AVCBH324245ZKER	CPZPNIVV

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



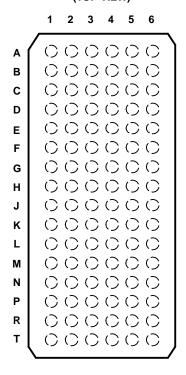
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Widebus+, DOC are trademarks of Texas Instruments.



SCES550B-FEBRUARY 2004-REVISED JUNE 2005

GKE PACKAGE (TOP VIEW)



TERMINAL ASSIGNMENTS

	1	2	3	4	5	6
Α	1B2	1B1	1DIR	1 OE	1A1	1A2
В	1B4	1B3	GND	GND	1A3	1A4
С	1B6	1B5	V _{CCB}	V _{CCA}	1A5	1A6
D	1B8	1B7	GND	GND	1A7	1A8
E	2B2	2B1	GND	GND	2A1	2A2
F	2B4	2B3	V_{CCB}	V_{CCA}	2A3	2A4
G	2B6	2B5	GND	GND	2A5	2A6
Н	2B7	2B8	2DIR	2 OE	2A8	2A7
J	3B2	3B1	3DIR	3 OE	3A1	3A2
K	3B4	3B3	GND	GND	3A3	3A4
L	3B6	3B5	V_{CCB}	V_{CCA}	3A5	3A6
М	3B8	3B7	GND	GND	3A7	3A8
N	4B2	4B1	GND	GND	4A1	4A2
Р	4B4	4B3	V _{CCB}	V _{CCA}	4A3	4A4
R	4B6	4B5	GND	GND	4A5	4A6
Т	4B7	4B8	4DIR	4 OE	4A8	4A7

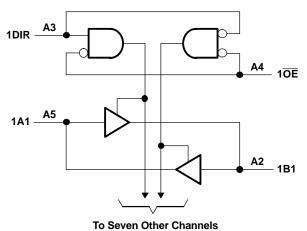


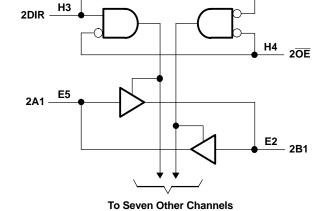
SCES550B-FEBRUARY 2004-REVISED JUNE 2005

FUNCTION TABLE (EACH 8-BIT SECTION)

INP	UTS	OPERATION
ŌĒ	DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	X	Isolation

LOGIC DIAGRAM (POSITIVE LOGIC)



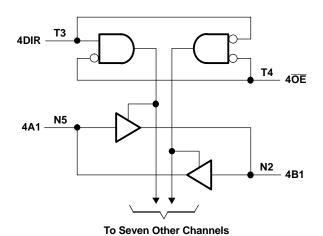


3DIR J3

J4 3OE

3A1 J2 3B1

To Seven Other Channels





SCES550B-FEBRUARY 2004-REVISED JUNE 2005

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CCA} V _{CCB}	Supply voltage range		-0.5	4.6	V
		I/O port (A port)	-0.5	4.6	
VI	Input voltage range ⁽²⁾	I/O port (B port)	-0.5	4.6	V
		Control inputs	-0.5	4.6	
V	Voltage range applied to any output in the high-impedance or	A port	-0.5	4.6	V
Vo	power-off state ⁽²⁾	B port	-0.5	4.6	V
	Valence and an alicelyte and the second section of the second section (2)(3)	A port	-0.5	V _{CCA} + 0.5	V
Vo	Voltage range applied to any output in the high or low state (2)(3)	B port	-0.5	V _{CCB} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through each V _{CCA} , V _{CCB} , or GND			±100	mA
θ_{JA}	Package thermal impedance ⁽⁴⁾	GKE/ZKE package		40	°C/W
T _{stg}	Storage temperature range	·	-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating" conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The input voltage and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The output positive-voltage rating may be exceeded up to 4.6 v maximum in (4) The package thermal impedance is calculated in accordance with JESD 51-7. The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current rating is observed.



SCES550B-FEBRUARY 2004-REVISED JUNE 2005

Recommended Operating Conditions (1)(2)(3)

			V _{CCI}	V _{cco}	MIN	MAX	UNIT
V_{CCA}	Supply voltage				1.4	3.6	V
V _{CCB}	Supply voltage				1.4	3.6	V
			1.4 V to 1.95 V		V _{CCI} × 0.65	3.6	
V_{IH}	High-level input voltage	Data inputs	1.95 V to 2.7 V		1.7	3.6	V
			2.7 V to 3.6 V		2	3.6	
			1.4 V to 1.95 V		0	$V_{\rm CCI} \times 0.35$	
V_{IL}	Low-level input voltage	Data inputs	1.95 V to 2.7 V		0	0.7	V
			2.7 V to 3.6 V		0	0.8	
		_	1.4 V to 1.95 V		V _{CCB} × 0.65	V _{CCB}	
V_{IH}	High-level input voltage	Control inputs (referenced to V _{CCB})	1.95 V to 2.7 V		1.7	V_{CCB}	V
		(referenced to vCCB)	2.7 V to 3.6 V		2	V _{CCB}	
		_	1.4 V to 1.95 V		0	$V_{CCB} \times 0.35$	
V_{IL}	Low-level input voltage	Control inputs (referenced to V _{CCB})	1.95 V to 2.7 V		0	0.7	V
		(referenced to ACCB)	2.7 V to 3.6 V		0	0.8	
Vo	Output voltage				0	V _{cco}	V
				1.4 V to 1.6 V		-2	
	High lovel output ourrent			1.65 V to 1.95 V		-4	mA
I _{OH}	High-level output current			2.3 V to 2.7 V		-8	mA
				3 V to 3.6 V		-12	
				1.4 V to 1.6 V		2	
	Laurianal andand annoat			1.65 V to 1.95 V		4	A
I _{OL}	Low-level output current			2.3 V to 2.7 V		8	mA
				3 V to 3.6 V		12	
Δt/Δν	Input transition rise or fa	II rate				5	ns/V
T _A	Operating free-air tempe	rature			-40	85	°C

 V_{CCI} is the V_{CC} associated with the data input port. V_{CCO} is the V_{CC} associated with the output port. All unused data inputs of the device must be held at V_{CCI} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



SCES550B-FEBRUARY 2004-REVISED JUNE 2005

Electrical Characteristics(1)

over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER	TEST COND	ITIONS	V _{CCA}	V _{CCB}	MIN	TYP ⁽²⁾	MAX	UNIT
		$I_{OH} = -100 \mu A$,	$V_I = V_{IH}$	1.4 V to 3.6 V	1.4 V to 3.6 V	$V_{\rm CCO}-0.2$			
		$I_{OH} = -2 \text{ mA},$	$V_I = V_{IH}$	1.4 V	1.4 V	1.05			
V_{OH}		$I_{OH} = -4 \text{ mA},$	$V_I = V_{IH}$	1.65 V	1.65 V	1.2			V
		$I_{OH} = -8 \text{ mA},$	$V_I = V_{IH}$	2.3 V	2.3 V	1.75			
		$I_{OH} = -12 \text{ mA},$	$V_I = V_{IH}$	3 V	3 V	2.3			
		$I_{OH} = 100 \mu A$,	$V_I = V_{IL}$	1.4 V to 3.6 V	1.4 V to 3.6 V			0.2	
		I _{OH} = 2 mA,	$V_I = V_{IL}$	1.4 V	1.4 V			0.35	
V_{OL}		$I_{OH} = 4 \text{ mA},$	$V_I = V_{IL}$	1.65 V	1.65 V			0.45	V
		I _{OH} = 8 mA,	$V_I = V_{IL}$	2.3 V	2.3 V			0.55	
		I _{OH} = 12 mA,	$V_I = V_{IL}$	3 V	3 V			0.7	
		$I_{OHD} = -6 \text{ mA},$	$V_I = V_{IH}$	1.4 V	1.4 V	1.05			
		$I_{OHD} = -9 \text{ mA},$	$V_I = V_{IH}$	1.65 V	1.65 V	1.2			.,
V_{OH}		$I_{OHD} = -15 \text{ mA},$	$V_I = V_{IH}$	2.3 V	2.3 V	1.75			V
		$I_{OHD} = -24 \text{ mA},$	$V_I = V_{IH}$	3 V	3 V	2.3			
		$I_{OHD} = 6 \text{ mA},$	$V_I = V_{IL}$	1.4 V	1.4 V			0.35	
		$I_{OHD} = 9 \text{ mA},$	$V_I = V_{IL}$	1.65 V	1.65 V			0.45	.,
V_{OL}		I _{OHD} = 15 mA,	$V_I = V_{IL}$	2.3 V	2.3 V			0.55	V
		I _{OHD} = 24 mA,	$V_I = V_{IL}$	3 V	3 V			0.7	
II	Control inputs	$V_I = V_{CCB}$ or GND		1.4 V to 3.6 V	3.6 V			±2.5	μΑ
		V _I = 0.49 V		1.4 V	1.4 V		11		
. (3)		V _I = 0.57 V		1.65 V	1.65 V	25			
I _{BHL} ⁽³⁾		V _I = 0.7 V		2.3 V	2.3 V	45			μΑ
		V _I = 0.8 V		3 V	3 V	75			
		V _I = 0.49 V		1.4 V	1.4 V		-11		
ı (4)		V _I = 1.07 V		1.65 V	1.65 V	-25			
I _{BHH} ⁽⁴⁾		V _I = 1.7 V		2.3 V	2.3 V	-45			μΑ
		V _I = 2 V		3 V	3 V	–7 5			
				1.6 V	1.6 V	100			
. (5)		$V_I = 0$ to V_{CC}		1.95 V	1.95 V	200			^
I _{BHLO} ⁽⁵⁾		AI = O 10 ACC		2.7 V	2.7 V	300			μΑ
				3.6 V	3.6 V	525	-		
				1.6 V	1.6 V	-100			
ı (6)		V = 0 to V		1.95 V	1.95 V	-200			^
I _{BHHO} ⁽⁶⁾		$V_I = 0$ to V_{CC}		2.7 V	2.7 V	-300			μΑ
				3.6 V	3.6 V	-525			

⁽¹⁾ V_{CCO} is the V_{CC} associated with the output port. (2) All typical values are at $T_A = 25^{\circ}C$.

The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND

and then raising it to V_{IL} max.

The bus-hold circuit can source at least the minimum high sustaining current at V_{IH} min. I_{BHH} should be measured after raising V_{IN} to (4) The bushfold direct can source at least the minimum high sectioning section at 1.
 (5) An external driver must source at least I_{BHLO} to switch this node from low to high.
 (6) An external driver must sink at least I_{BHHO} to switch this node from high to low.



SCES550B-FEBRUARY 2004-REVISED JUNE 2005

Electrical Characteristics(1)(2) (continued)

over recommended operating free-air temperature range (unless otherwise noted)

1	A port							
		\/ -=\/ 0.45.2.6.\/		0 V	0 to 3.6 V		±10	^
l _{off}	B port	V_I or $V_O = 0$ to 3.6 V		0 to 3.6 V	0 V		±10	μΑ
	A or B port		OE = V _{IH}	3.6 V	3.6 V		±12.5	
$I_{OZ}^{(4)}$	B port	$V_O = V_{CCO}$ or GND, $V_I = V_{CCI}$ or GND	OE = don't	0 V	3.6 V		±12.5	μΑ
	A port	VI = VCCI 01 011D	care	3.6 V	0 V		±12.5	
			·	1.6 V	1.6 V		40	
				1.95 V	1.95 V		40	
		V V or CND		2.7 V	2.7 V		60	^
I _{CCA}		$V_I = V_{CCI}$ or GND,	$I_{O} = 0$	0 V	3.6 V		-80	μΑ
				3.6 V	0 V		80	
				3.6 V	3.6 V		80	
				1.6 V	1.6 V		40	
				1.95 V	1.95 V		40	
		$V_I = V_{CCI}$ or GND,	I - 0	2.7 V	2.7 V		60	^
I _{CCB}		$v_1 = v_{CCI}$ or GND,	$I_O = 0$	0 V	3.6 V		80	μΑ
				3.6 V	0 V		-80	
				3.6 V	3.6 V		80	
C _i	Control inputs	V _I = 3.3 V or GND		3.3 V	3.3 V	4		pF
C _{io}	A or B ports	$V_O = 3.3 \text{ V or GND}$		3.3 V	3.3 V	5		pF

- V_{CCO} is the V_{CC} associated with the output port. V_{CCI} is the V_{CC} associated with the input port. All typical values are at T_A = 25°C. For I/O ports, the parameter I_{OZ} includes the input leakage current.

Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$ (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = ± 0.		V _{CCB} = 1.8 V ± 0.15 V		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		UNIT
	(INFOT)	(001701)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	Α	В	1.7	6.7	1.9	6.4	1.8	5.5	1.5	5.8	20
t _{pd}	В	A	1.8	6.8	1.7	6.2	1.6	5.9	1.5	5.9	ns
4	ŌĒ	A	2.1	9	2.9	9.8	3.2	10	3	9.8	20
^l en	OE	В	2.5	8.4	2.4	8	2.3	7.6	2.2	7.5	ns
	ŌĒ	Α	2.1	7.1	2.3	6.4	1.7	5.1	1.6	4.8	20
t _{dis}	OE .	В	2.2	6.9	1.8	6.4	1.1	5.8	1.8	5.7	ns

Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.5 V ± 0.1 V		V _{CCB} = 1.8 V ± 0.15 V		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		UNIT
	(INFOT)	(001701)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	Α	В	1.7	6.4	1.8	6	1.7	4.7	1.6	4.3	20
t _{pd}	В	А	2	6.6	1.8	6	1.8	5.6	1.8	5.5	ns
	ŌĒ	А	1.8	7.6	2.6	7.7	2.6	7.6	2.6	7.4	
t _{en}	OE	В	2.5	8.2	2.5	7.5	2.4	7.4	2.3	7.2	ns
	ŌĒ	Α	1.8	7	2.5	6.3	1.8	4.7	1.7	4.4	20
t _{dis}	OE .	В	2.5	6.7	2.3	6.1	2.2	5.5	1.3	5.3	ns

TEXAS INSTRUMENTS www.ti.com

SCES550B-FEBRUARY 2004-REVISED JUNE 2005

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 2.5 V \pm 0.2 V (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = ± 0.7		V _{CCB} = ± 0.1		V _{CCB} = ± 0.2		V _{CCB} = ± 0.3		UNIT
	(INFOT)	(001701)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
4	Α	В	1.6	6	1.8	5.6	1.5	4	1.5	3.4	no
t _{pd}	В	Α	1.7	5.4	1.7	4.6	1.5	4	1.5	3.7	ns
4	ŌĒ	Α	1.7	5.7	2.2	5.5	2.2	5.3	2.2	5.1	no
t _{en}	OE	В	3.1	6.1	2.5	5.6	2.2	5.3	1.9	4.2	ns
4	ŌĒ	Α	1.2	5.8	1.9	5	1.4	3.6	1.3	3.3	no
t _{dis}	OE .	В	2.4	6	3	5.2	1.4	3.6	1.2	3	ns

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 3.3 V ± 0.3 V (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)		V _{CCB} = 1.5 V ± 0.1 V		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		UNIT	
	(INFOT)	(001701)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	Α	В	1.5	5.9	1.7	5.4	1.5	3.7	1.4	3.1	20
t _{pd}	В	Α	1.5	5.8	1.5	4.2	1.5	3.3	1.4	3.1	ns
	ŌĒ	Α	1.6	4.9	2	4.5	2	4.3	1.9	4.1	20
t _{en}	OE	В	2	5.1	2	4.6	2.2	5.2	1.9	4.1	ns
	ŌĒ	Α	1.3	6.9	2.1	5.5	1.6	3.8	1.5	3.5	20
t _{dis}	OE .	В	2.3	5.5	1.9	4.5	1.3	3.5	1.2	3.5	ns

Operating Characteristics

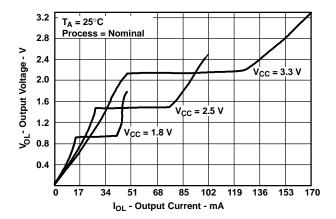
 V_{CCA} and V_{CCB} = 3.3 V, T_{A} = 25°C

	PARAMETER		TEST C	CONDITIONS	TYP	UNIT
	Power-dissipation capacitance per transceiver,	Outputs enabled			14	
C _{pdA}	A-port input, B-port output	Outputs disabled	C - 0	f = 10 MHz	7	pF
$C_{pdA} (V_{CCA})$	Power-dissipation capacitance per transceiver,	Outputs enabled	$C_L = 0,$	I = 10 WINZ	20	рг
	B-port input, A-port output	Outputs disabled			7	
	Power-dissipation capacitance per transceiver,	Outputs enabled			20	
C _{ndB}	A-port input, B-port output	Outputs disabled		f = 10 MHz	7	~F
C_{pdB} (V_{CCB})	Power-dissipation capacitance per transceiver,	Outputs enabled	$C_L = 0,$	I = 10 WINZ	14	pF
	B-port input, A-port output	Outputs disabled			7	

SCES550B-FEBRUARY 2004-REVISED JUNE 2005

Output Description

The DOCTM circuitry is implemented, which, during the transition, initially lowers the output impedance to effectively drive the load and, subsequently, raises the impedance to reduce noise. Figure 1 shows typical V_{OL} vs I_{OL} and V_{OH} vs I_{OH} curves to illustrate the output impedance and drive capability of the circuit. At the beginning of the signal transition, the DOC circuit provides a maximum dynamic drive that is equivalent to a high-drive standard-output device. For more information, refer to the TI application reports, *AVC Logic Family Technology and Applications*, literature number SCEA006, and *Dynamic Output Control (DOC*TM) *Circuitry Technology and Applications*, literature number SCEA009.



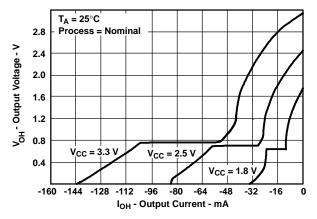
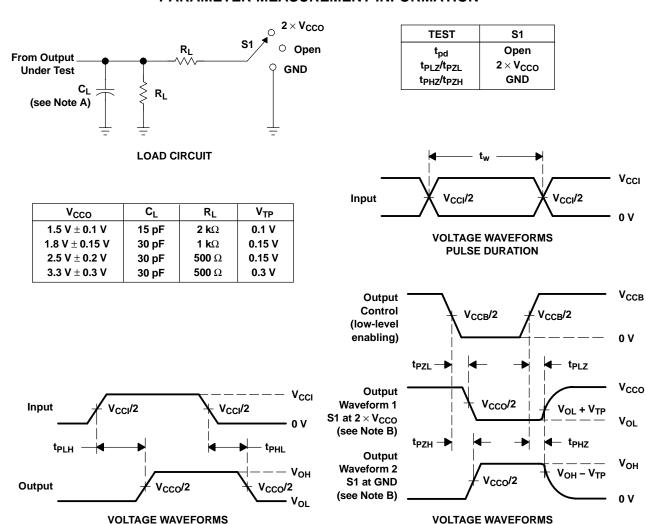


Figure 1. Typical Output Voltage vs Output Current



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.

ENABLE AND DISABLE TIMES

- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_0 = 50 Ω , $dv/dt \geq$ 1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. V_{CCI} is the V_{CC} associated with the input port.
- I. V_{CCO} is the V_{CC} associated with the output port.

PROPAGATION DELAY TIMES

Figure 2. Load Circuit and Voltage Waveforms





i.com 13-Oct-2008

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
74AVCBH324245ZKER	ACTIVE	LFBGA	ZKE	96	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR
SN74AVCBH324245KR	NRND	LFBGA	GKE	96	1000	TBD	SNPB	Level-2-235C-1 YEAR

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

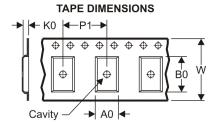
Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74AVCBH324245ZKER	LFBGA	ZKE	96	1000	330.0	24.4	5.7	13.7	2.0	8.0	24.0	Q1
SN74AVCBH324245KR	LFBGA	GKE	96	1000	330.0	24.4	5.7	13.7	2.0	8.0	24.0	Q1



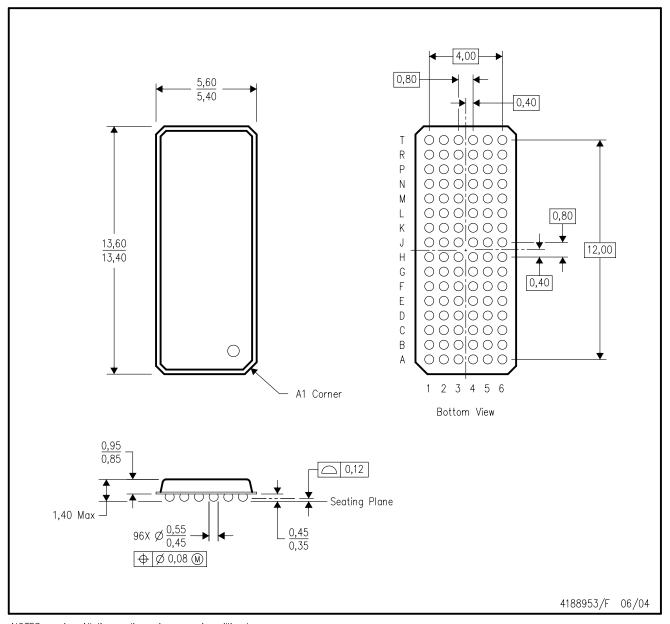


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
74AVCBH324245ZKER	LFBGA	ZKE	96	1000	346.0	346.0	41.0
SN74AVCBH324245KR	LFBGA	GKE	96	1000	346.0	346.0	41.0

GKE (R-PBGA-N96)

PLASTIC BALL GRID ARRAY



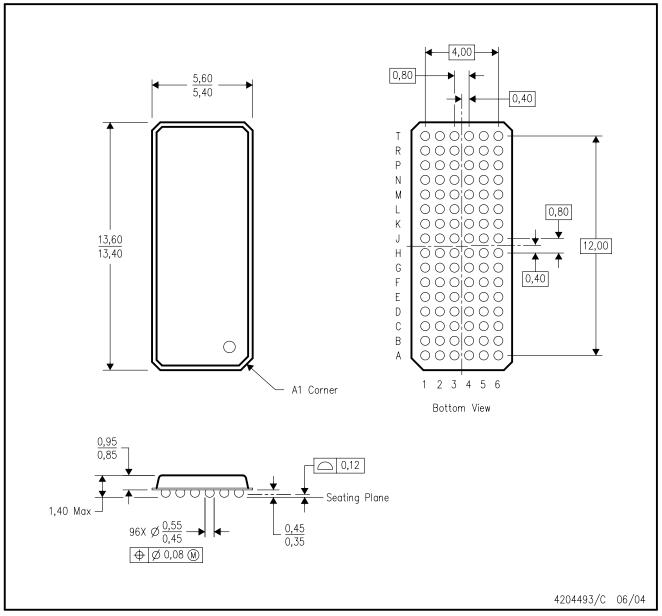
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-205 variation CC.
- D. This package is tin-lead (SnPb). Refer to the 96 ZKE package (drawing 4204493) for lead-free.



ZKE (R-PBGA-N96)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-205 variation CC.
- D. This package is lead-free. Refer to the 96 GKE package (drawing 4188953) for tin-lead (SnPb).



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products Amplifiers amplifier.ti.com Data Converters dataconverter.ti.com DSP dsp.ti.com Clocks and Timers www.ti.com/clocks Interface interface.ti.com Logic logic.ti.com Power Mgmt power.ti.com Microcontrollers microcontroller.ti.com www.ti-rfid.com RF/IF and ZigBee® Solutions www.ti.com/lprf

Applications	
Audio	www.ti.com/audio
Automotive	www.ti.com/automotive
Broadband	www.ti.com/broadband
Digital Control	www.ti.com/digitalcontrol
Medical	www.ti.com/medical
Military	www.ti.com/military
Optical Networking	www.ti.com/opticalnetwork
Security	www.ti.com/security
Telephony	www.ti.com/telephony
Video & Imaging	www.ti.com/video
Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2008, Texas Instruments Incorporated